Features

- Trench MOSFET Technology
- Moisture Sensitivity Level 1
- Halogen Free. “Green” Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-CHANNEL MOSFET

Maximum Ratings

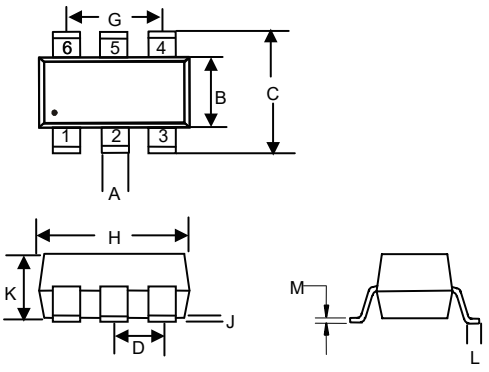
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 70°C/W Junction to Ambient(Note2)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Volltage		V_{GS}	±12	V
Continuous Drain Current	T_A=25°C	I_D	5.8	A
	T_A=100°C		3.7	
Pulsed Drain Current(Note3)		I_{DM}	23.2	A
Total Power Dissipation(Note4)		P_D	1.8	W

Note:

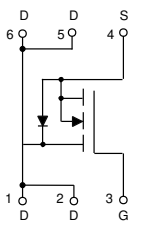
1. Halogen free "Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

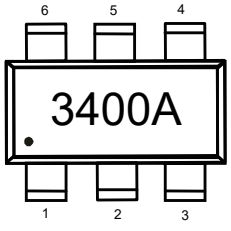
SOT23-6L



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.012	0.020	0.30	0.50	
B	0.051	0.070	1.30	1.80	
C	0.087	0.126	2.20	3.20	
D	0.037		0.95		TYP.
G	0.074		1.90		TYP.
H	0.106	0.122	2.70	3.10	
J	0.002	0.006	0.05	0.15	
K	0.030	0.051	0.75	1.30	
L	0.012	0.024	0.30	0.60	
M	0.003	0.008	0.08	0.22	

Internal Structure and Marking Code





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS}=0V, I_D=250μA	30			V
Gate-Body Leakage Current	I_{GSS}	V_{GS}=±12V, V_{DS}=0V			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=30V, V_{GS}=0V			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250μA	0.5	0.9	1.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=5.8A		20	32	mΩ
		V_{GS}=4.5V, I_D=5A		21.5	38	
		V_{GS}=2.5V, I_D=4A		26	45	
Forward Transconductance	g_{fs}	V_{DS}=5V, I_D=5A		20		S
Gate Resistance	R_g	f=1 MHz, Open drain		12		Ω
Diode Characteristics						
Diode Forward Current	I_S				5.8	A
Diode Forward Voltage	V_{SD}	V_{GS}=0V, I_s=5.6A			1.2	V
Reverse Recovery Time	t_{rr}	I_F=5.6A,di/dt=100A/us		10		nS
Reverse Recovery Charge	Q_{rr}			3.7		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	V_{DS}=15V,V_{GS}=0V, f=1MHz		580		pF
Output Capacitance	C_{oss}			60		
Reverse Transfer Capacitance	C_{rss}			50		
Total Gate Charge	Q_g	V_{DS}=15V,V_{GS}=10V,I_D=5.6A		16.3		nC
Gate-Source Charge	Q_{gs}			2.2		
Gate-Drain Charge	Q_{gd}			2.1		
Turn-on Delay Time	$t_{d(on)}$	V_{DD}=15V,V_{GS}=10V , I_D=5.6A,R_G =3Ω		5.5		ns
Turn-on Rise Time	t_r			28.3		
Turn-off Delay Time	$t_{d(off)}$			24.8		
Turn-off Fall Time	t_f			13.7		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

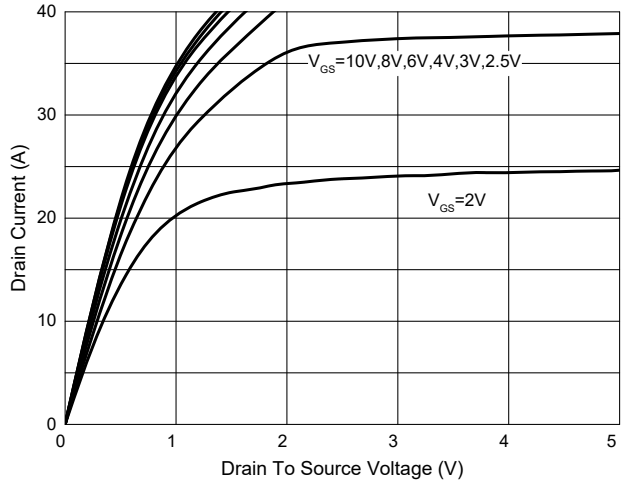


Fig. 2 - Transfer Characteristics

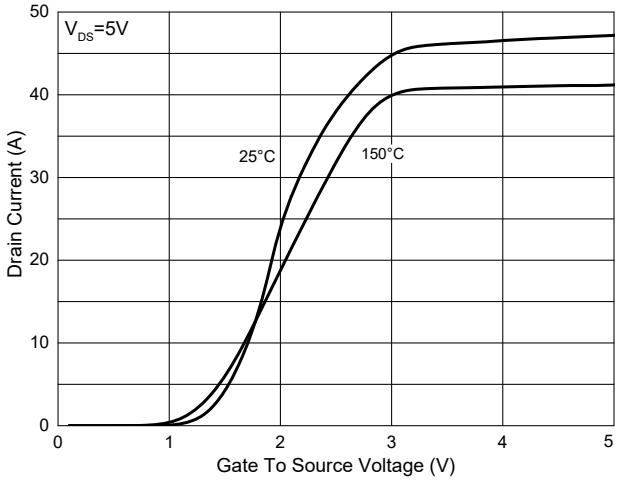


Fig. 3 - $R_{DS(ON)}$—V_{GS}

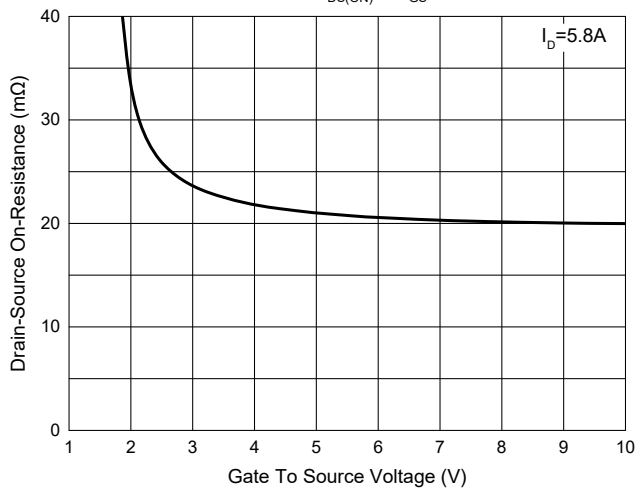


Fig. 4 - $R_{DS(ON)}$—I_D

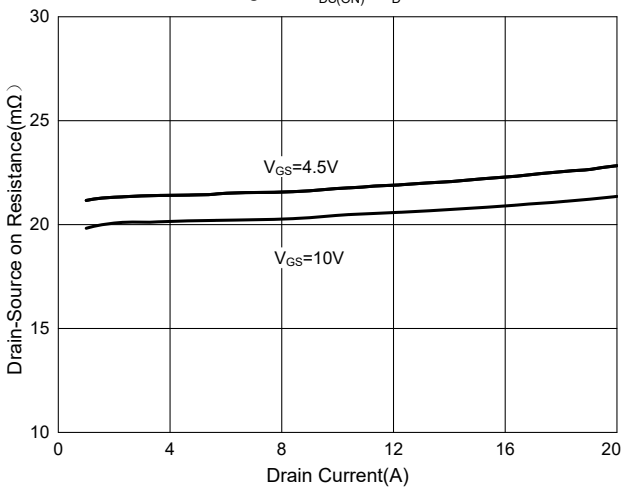


Fig. 5 - Capacitance Characteristics

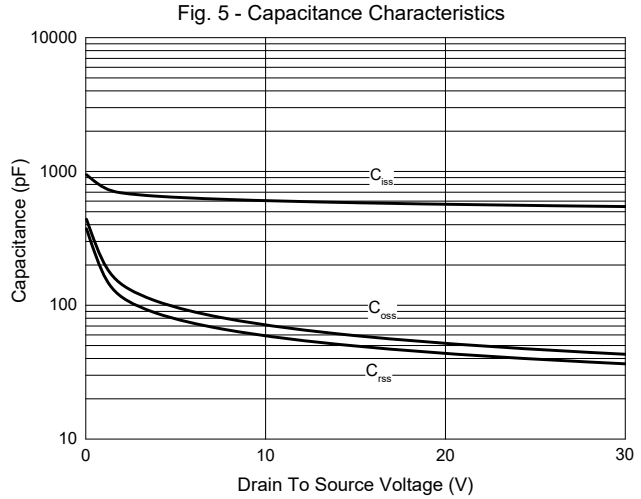
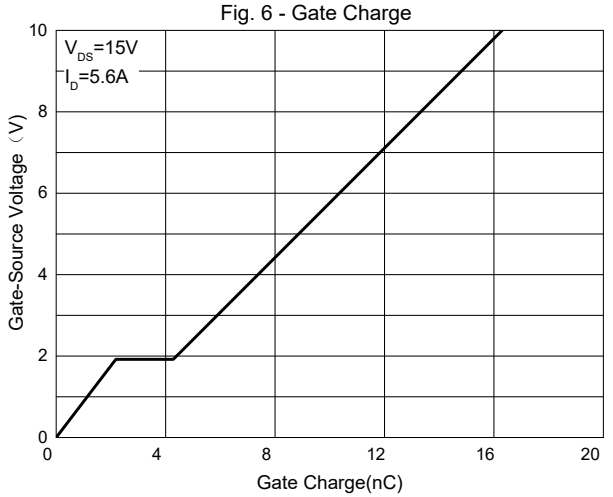


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Nomalized Threshold Voltage

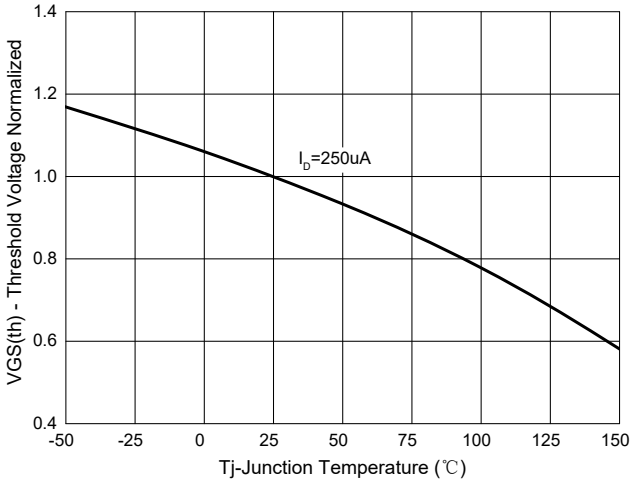


Fig.8-Normalized On Resistance Characteristics

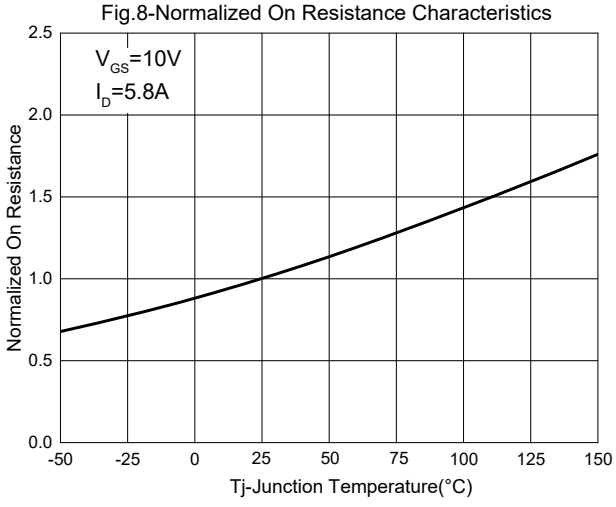


Fig.9 - I_S—V_{SD}

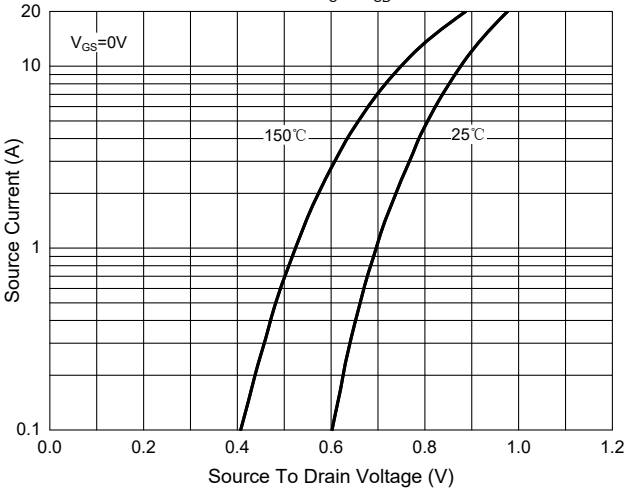


Fig. 10 - Drain Current

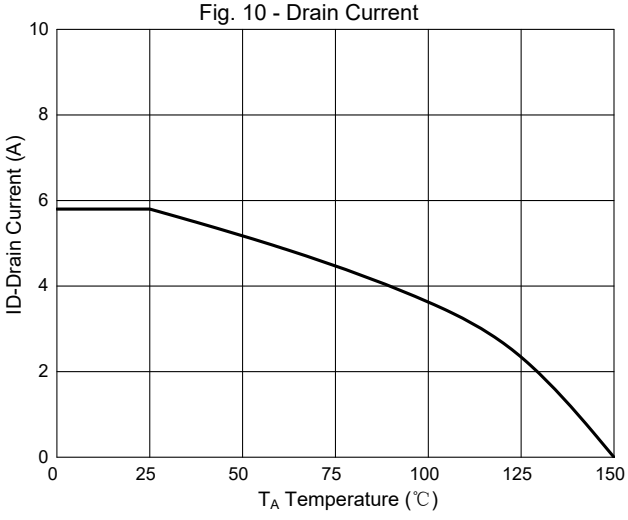
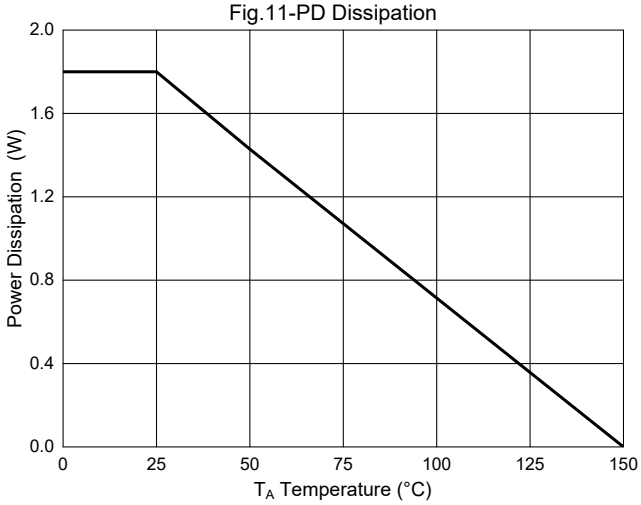


Fig.11-PD Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

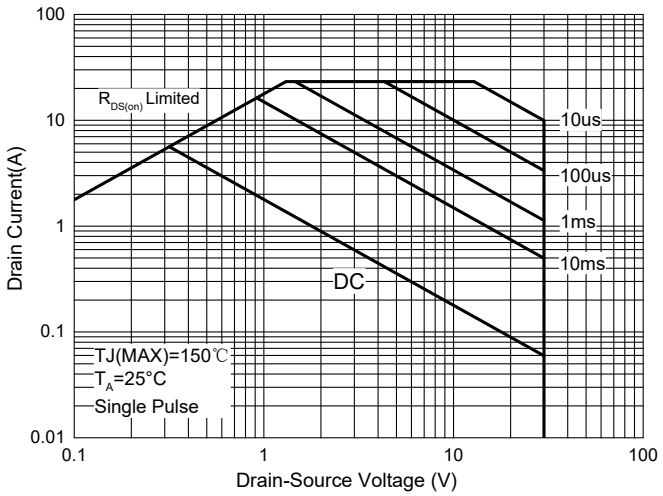
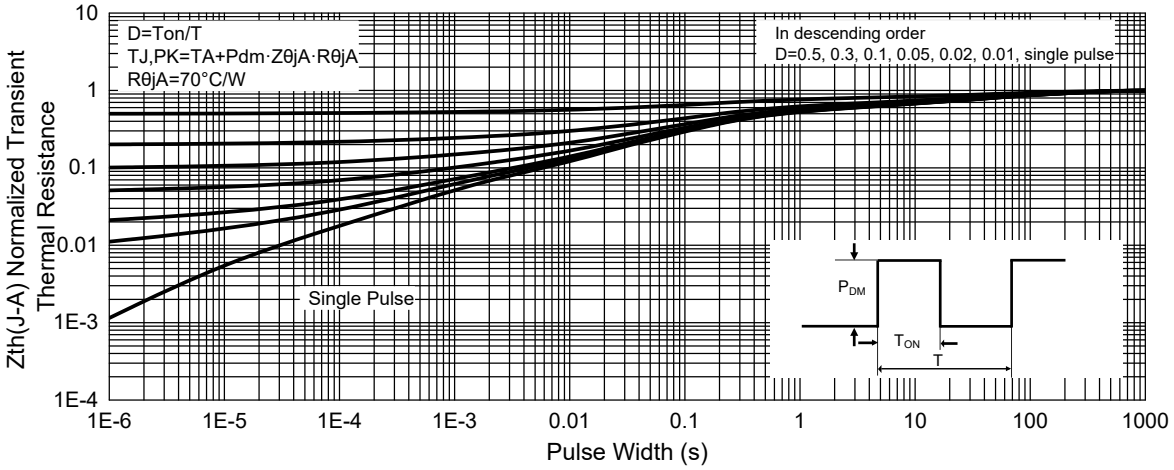


Fig. 13 -Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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